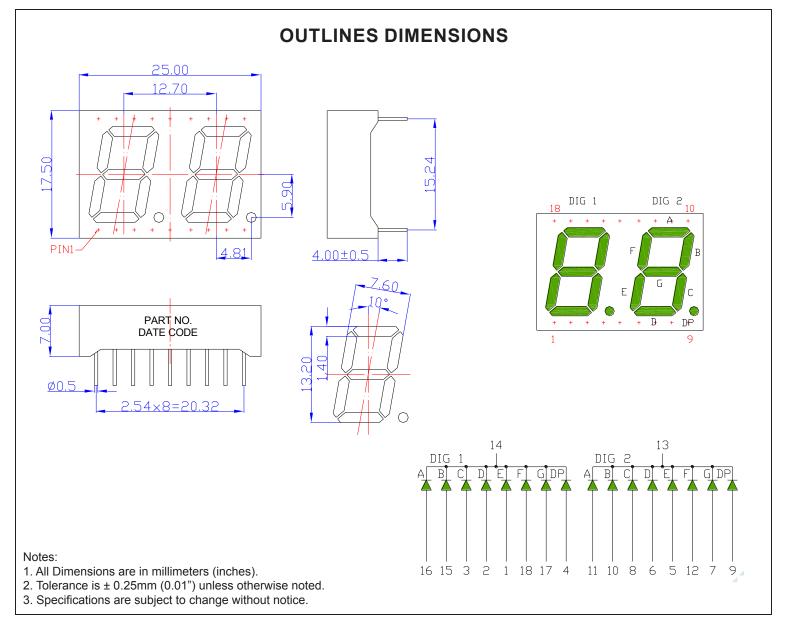


SPECIFICATIONS

CDDC52G2WBF



Part Number	Chip Material	Color of Emission	Lens Type	Description	
CDDC52G2WBF	InGaAIP	Green	White Seg/Black Face	Common Cathode	





ABSOLUTE MAXIMUM RATINGS

(TA=25°C)

Parameter	Symbol	Max Rating	Unit			
Power Dissipation	PD	85	mW			
Pulse Forward Current	lfp	120	mA			
Continuous Forward Current	lF	30	mA			
Reverse Voltage Segment	VR	5	V			
Operating Temperature Range	Topr	-25~+85	°C			
Storage Temperature Range	Тѕтс	-25~+85	°C			
IFP = Pulse Width \leq 10 ms, Duty Ratio \leq 1/10. Soldering Condition: 260 °C/ 5sec						

OPTICAL-ELECTRICAL CHARACTERISTICS

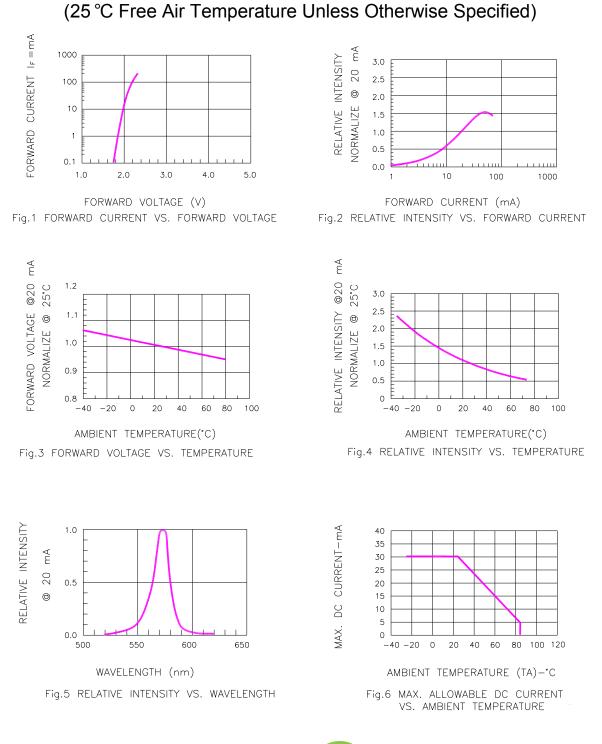
(TA=25°C)

Deremeter	Symbol	Test Condition	Value			Linit
Parameter			Min	Тур	Max	Unit
Luminous Intensity	١v	l⊧ = 20mA	-	25	-	mcd
Forward Voltage	Vf	l⊧ = 20mA	-	2.1	2.6	V
Reverse Leakage Current	lr	V _R = 5V	-	-	10	μA
Peak Wavelength	λP	l⊧ = 20mA	-	573	-	nm
Dominant Wavelength	λD	l⊧ = 20mA	566	571	574	nm
Spectral Radiation Bandwidth	Δλ	l⊧ = 20mA	-	20	-	nm





OPTICAL CHARACTERISTIC CURVES

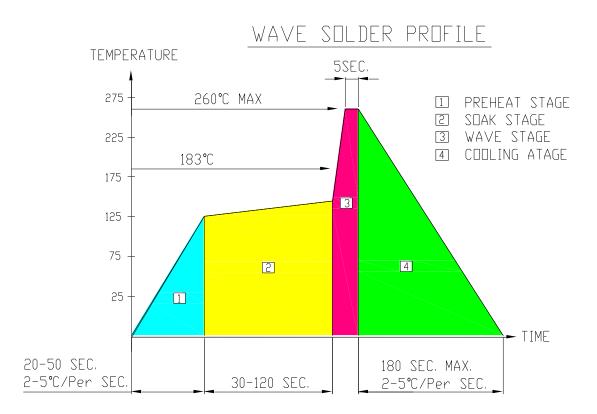


RoHS Compliant



SOLDERING CONDITIONS – DISPLAY TYPE LED

• RECOMMEND SOLDERING PROFILE



SOLDERING IRON

Basic spec is \leq 4 sec when 260°C. If temperature is higher, time should be shorter (+10°C→1 sec). Power dissipation of Iron should be smaller than 15W, and temperature should be controllable. Surface temperature of the device should be under 230°C.

REWORK

Customer must finish rework within ≦4 sec under 245°C.

